TLE7272-2

5-V Low Dropout Voltage Regulator

Automotive Power





5-V Low Dropout Voltage Regulator

TLE7272-2





1 Overview

Features

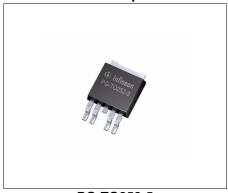
- Ultra Low Current Consumption 20 μA
- Output Voltage 5 V ±2%
- · Output Current up to 300 mA
- · Power-On and Undervoltage Reset
- Reset Low Down to V_Q = 1 V
- Enable Input
- Very Low Dropout Voltage
- Output Current Limitation
- · Overtemperature Shutdown
- Wide Temperature Range From -40 °C up to 150 °C
- Green Product (RoHS compliant)
- AEC Qualified

Description

The TLE7272-2 is a monolithic integrated low dropout voltage regulator for load currents up to 300 mA. An input voltage up to 42 V is regulated to $V_{\rm Q,nom}$ = 5.0 V with a precision of ±2%. Due to its integrated reset circuitry featuring power on timing and output voltage monitoring the IC is well suited as μ -controller supply. The sophisticated design allows to achieve stable operation even with ceramic output capacitors down to 470 nF. The device is designed for the harsh environment of automotive



PG-SSOP-14 Exposed Pad



PG-TO252-5

applications. Therefore it is protected against overload, short circuit and overtemperature conditions by the implemented output current limitation and the overtemperature shutdown circuit. The TLE7272-2 can be also used in all other applications requiring a stabilized 5 V voltage.

Due to its ultra low quiescent current of typically 20 μ A the TLE7272-2 is dedicated for use in applications permanently connected to V_{BAT} . In addition the device can be switched off via the Enable input reducing the current consumption to typically 5 μ A. An integrated output sink current circuitry keeps the voltage at the Output pin Q below 5.5 V even in case of occuring reverse currents. Thus connected devices are protected from overvoltage damage. For applications requiring extremely low noise levels the Infineon voltage regulator family TLE 42XX and TLE 44XX is more suited than the TLE7272-2. A mV-range output noise on the TLE7272-2 caused by the charge pump operation is unavoidable due to the ultra low quiescent current concept.

Туре	Package	Marking
TLE7272-2E	PG-SSOP-14 Exposed Pad	7272-2E
TLE7272-2D	PG-TO252-5	7272-2D



Block Diagram

2 Block Diagram

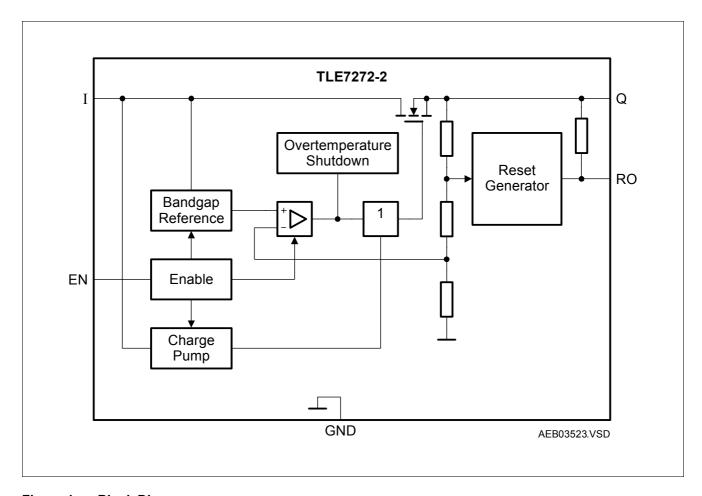


Figure 1 Block Diagram



Pin Configuration

3 Pin Configuration

3.1 Pin Assignment PG-SSOP-14 Exposed Pad

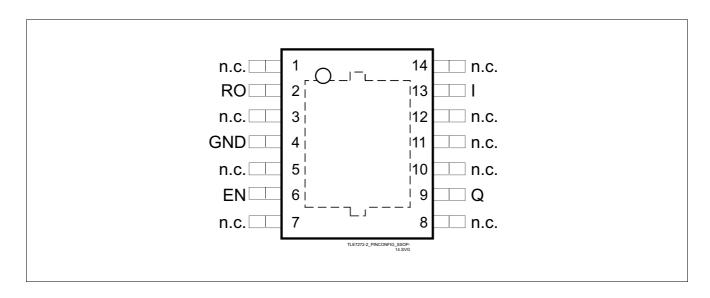


Figure 2 Pin Configuration (top view)

3.2 Pin Definitions and Functions PG-SSOP-14 Exposed Pad

Pin No.	Symbol	Function
1,3,5,7	n.c.	non connected
		can be open or connected to GND
2	RO	Reset Output
		open collector output with integrated pull-up resistor;
		optional external pull-up resistor of \geq 10 k Ω to pin Q;
		leave open if reset function not needed
4	GND	Ground
6	EN	Enable Input
		high level input signal enables the IC;
		low level input signal disables the IC;
		integrated pull-down resistor
8,10,11,12,14	n.c.	non connected
		can be open or connected to GND
9	Q	Output
		block to ground with a capacitor close to the IC terminals, respecting the values given
		for its capacitance and ESR in "Functional Range" on Page 6
13	I	Input
		block to ground directly at the IC with a ceramic capacitor
Pad	_	Exposed Pad
		connect to GND and heatsink area



Pin Configuration

3.3 Pin Assignment PG-TO252-5

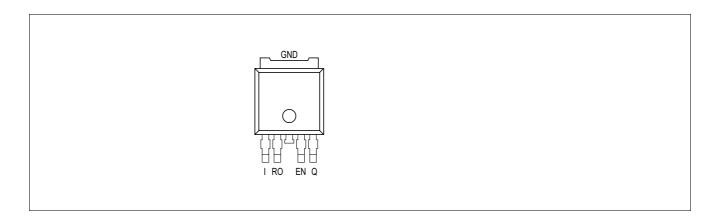


Figure 3 Pin Configuration (top view)

3.4 Pin Definitions and Functions PG-TO252-5

Pin No.	Symbol	Function
1	I	Input
		block to ground directly at the IC with a ceramic capacitor
2	RO	Reset Output
		open collector output with integrated pull-up resistor;
		optional external pull-up resistor of \geq 10 k Ω to pin Q;
		leave open if reset function not needed
3	GND	Ground
		internally connected to heat slug
4	EN	Enable Input
		high level input signal enables the IC;
		low level input signal disables the IC;
		integrated pull-down resistor
5	Q	Output
		block to ground with a capacitor close to the IC terminals, respecting the values given
		for its capacitance and ESR in "Functional Range" on Page 6
Heat Slug	_	Heat Slug
		internally connected to GND;
		connect to GND and heatsink area



General Product Characteristics

4 General Product Characteristics

4.1 Absolute Maximum Ratings

Absolute Maximum Ratings¹⁾

 T_i = -40 °C to 150 °C; all voltages with respect to ground, (unless otherwise specified)

Pos.	Parameter	Symbol	Lin	Limit Values		Test Condition
			Min.	Max.		
Input I		-	-	-		
4.1.1	Voltage	V_1	-0.3	45	V	_
Output	Q, Reset Output RO	-	'	'	· ·	-
4.1.2	Voltage	$V_{\rm Q},V_{\rm RO}$	-0.3	6	V	_
4.1.3	Voltage	$V_{\rm Q},V_{\rm RO}$	-0.3	6.2	V	$t < 10 \text{ s}^{2)}$
Enable	Input EN		•	+	<u>'</u>	•
4.1.4	Voltage	V_{EN}	-0.3	45	V	_
Tempe	rature	•				•
4.1.5	Junction temperature	T_{j}	-40	150	°C	_
4.1.6	Storage temperature	T_{stg}	-50	150	°C	_
ESD St	usceptibility	•				•
4.1.7	Human Body Model (HBM) ³⁾	Voltage	-	3	kV	_
4.1.8	Charged Device Model (CDM) ⁴⁾	Voltage	-	1.5	kV	_

¹⁾ not subject to production test, specified by design

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

4.2 Functional Range

Pos.	Parameter	Symbol	Limit Values		Unit	Remarks	
			Min.	Max.			
4.2.1	Input voltage	V_1	5.5	42	V	_	
4.2.2	Output Capacitor's	C_{Q}	470	_	nF	1)	
4.2.3	Requirements	$ESR(C_{Q})$	_	10	Ω	2)	
4.2.4	Junction temperature	T_{j}	-40	150	°C	_	

¹⁾ the minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.

²⁾ exposure to these absolute maximum ratings for extended periods (t > 10 s) may affect device reliability

³⁾ ESD susceptibility Human Body Model "HBM" according to AEC-Q100-002 - JESD22-A114

⁴⁾ ESD susceptibility Charged Device Model "CDM" according to ESDA STM5.3.1

²⁾ relevant ESR value at f = 10 kHz



General Product Characteristics

4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

Pos.	Parameter	Symbol	1	Limit Val	ues	Unit	Conditions
			Min.	Тур.	Max.		
TLE72	72-2E (PG-SSOP-14 Exposed	Pad)	- 1			<u> </u>	1
4.3.1	Junction to Case ¹⁾	R_{thJC}	_	14	_	K/W	measured to exposed pad
4.3.2	Junction to Ambient ¹⁾	R_{thJA}	_	47	_	K/W	2)
4.3.3		R_{thJA}	_	141	_	K/W	footprint only ³⁾
4.3.4		R_{thJA}	_	66	-	K/W	300 mm² heatsink area ³⁾
4.3.5		R_{thJA}	_	56	-	K/W	600 mm² heatsink area ³⁾
TLE72	72-2D (PG-TO252-5)	1	- 1			<u> </u>	
4.3.1	Junction to Case ¹⁾	R_{thJC}	_	6	_	K/W	measured to tab
4.3.2	Junction to Ambient ¹⁾	R_{thJA}	_	32	_	K/W	2)
4.3.3		R_{thJA}	_	115	_	K/W	footprint only ³⁾
4.3.4		R_{thJA}	_	62	_	K/W	300 mm² heatsink area ³⁾
4.3.5		R_{thJA}	-	47	-	K/W	600 mm² heatsink area ³⁾

¹⁾ Not subject to production test, specified by design.

²⁾ Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70μm Cu, 2 x 35μm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

³⁾ Specified R_{thJA} value is according to Jedec JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 \times 114.3 \times 1.5 mm³ board with 1 copper layer (1 x 70 μ m Cu).



Electrical Characteristics 5

5.1 **Electrical Characteristics Voltage Regulator**

Electrical Characteristics

 $V_{\rm i}$ =13.5 V; $T_{\rm i}$ = -40 °C to 150 °C; all voltages with respect to ground (unless otherwise specified)

Pos.	Parameter	Symbol	Li	mit Val	ues	Unit	Measuring Condition
			Min.	Тур.	Max.		
Output	Q	1				- 1	
5.1.1	Output Voltage	V_{Q}	4.9	5.0	5.1	V	0.1 mA < I _Q <300 mA 6 V < V _I < 16 V
5.1.2	Output Voltage	V_{Q}	4.9	5.0	5.1	V	0.1 mA < I _Q <100 mA 6 V < V _I < 40 V
5.1.3	Dropout Voltage	V_{dr}	_	250	500	mV	$I_{\rm Q}$ = 200 mA $V_{\rm dr} = V_{\rm I} - V_{\rm Q}^{-1}$
5.1.4	Load Regulation	$\Delta V_{Q,lo}$	- 40	15	40	mV	$I_{\rm Q}$ = 5 mA to 250 mA
5.1.5	Line Regulation	$\Delta V_{Q, li}$	- 20	5	20	mV	$V_{\rm I}$ = 10 V to 32 V $I_{\rm Q}$ = 5 mA
5.1.6	Output Current Limitation	I_{Q}	301	_	_	mA	1)
5.1.7	Output Current Limitation	I_{Q}	_	_	800	mA	$V_{Q} = 0V$
5.1.8	Power Supply Ripple Rejection ²⁾	PSRR	_	60	_	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 Vpp
5.1.9	Temperature Output Voltage Drift	$\frac{dV_{Q}}{dT}$	_	0.5	-	mV/K	_
Curren	t Consumption	-1				- 1	
5.1.10	Quiescent Current $I_{q} = I_{l} - I_{Q}$	I_{q}	_	20	30	μΑ	$I_{\rm Q}$ = 0.1 mA; $V_{\rm EN}$ = 5 V $T_{\rm i}$ = 25 °C
5.1.11	Quiescent Current $I_q = I_1 - I_Q$	I_{q}	_	_	40	μΑ	$I_{\rm Q}$ = 0.1 mA; $V_{\rm EN}$ = 5 V $T_{\rm j} \le 80~{\rm ^{\circ}C}$
5.1.12	Current Consumption, Regulator Disabled	I_{q}	_	5	9	μA	$V_{\rm EN}$ = 0 V; $T_{\rm j}$ < 80°C

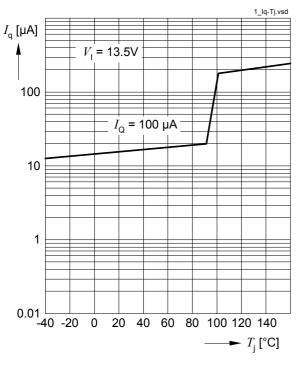
¹⁾ Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value obtained at $V_{\rm I}$ = 13.5 V.

²⁾ not subject to production test, specified by design

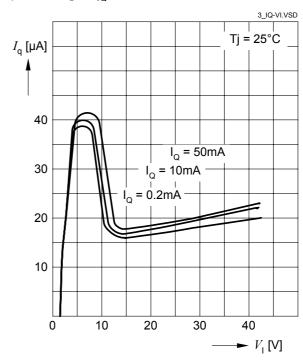


5.2 Typical Performance Characteristics Voltage Regulator

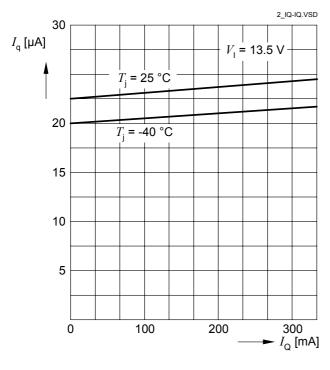
Current Consumption $I_{\rm q}$ versus Junction Temperature $T_{\rm J}$



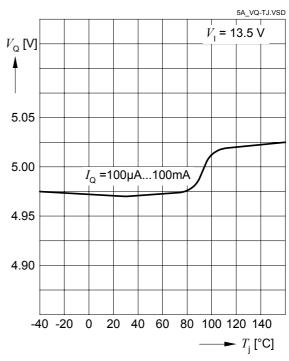
Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm IQ}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$

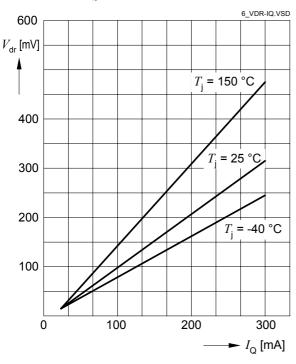


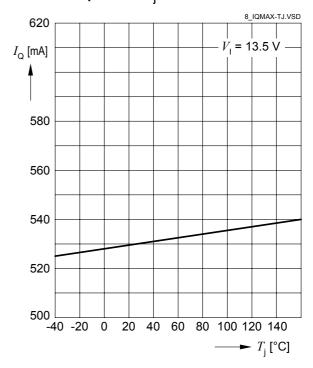
Output Voltage $V_{\rm Q}$ versus Junction Temperature $T_{\rm J}$



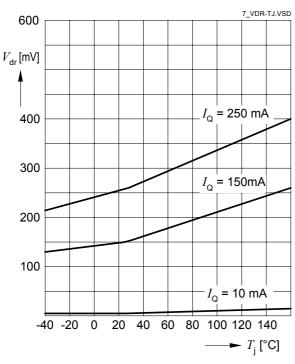


Dropout Voltage V_{dr} versus Output Current I_{Q}

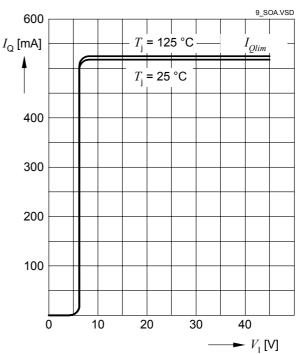




$\begin{tabular}{ll} {\bf Dropout\ Voltage\ $V_{\rm dr}$ versus} \\ {\bf Junction\ Temperature} \end{tabular}$

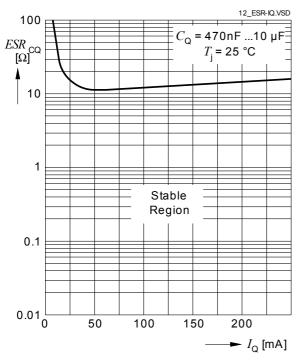


Maximum Output Current I_{Q} versus Input Voltage V_{I}

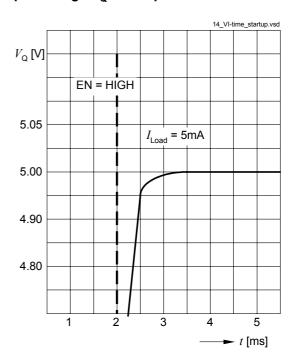




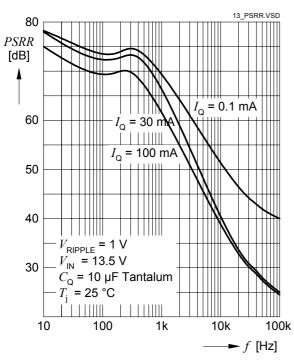
Region of Stability



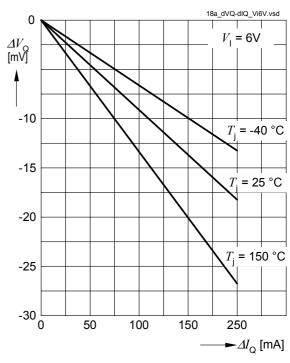
Output Voltage V_{Q} Start-up behavior



Power Supply Ripple Rejection PSRR versus Frequency f

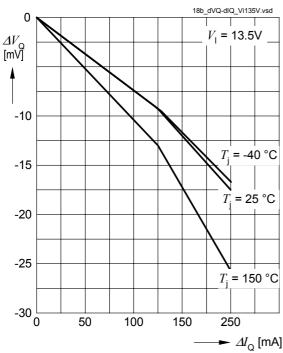


Load Regulation ΔV_{Q} versus Output Current Change ΔI_{Q}

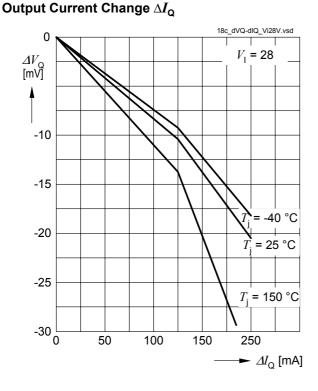




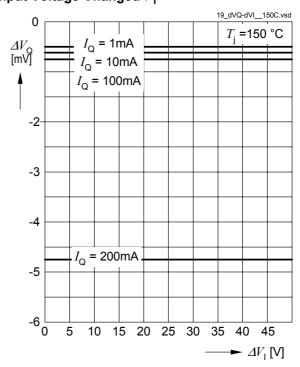
Load Regulation $\Delta V_{ m Q}$ versus Output Current Change $dI_{ m Q}$



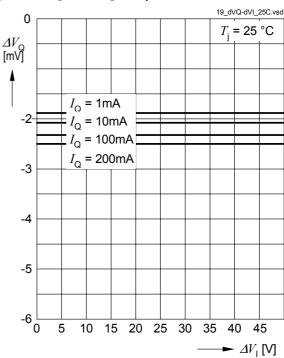
Load Regulation $\Delta V_{ extsf{Q}}$ versus



Line Regulation ΔV_{Q} versus Input Voltage Changed V_{I}

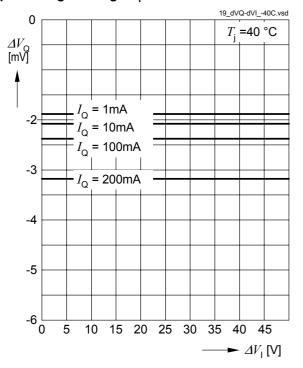


Line Regulation ΔV_{Q} versus Input Voltage Changed V_{I}

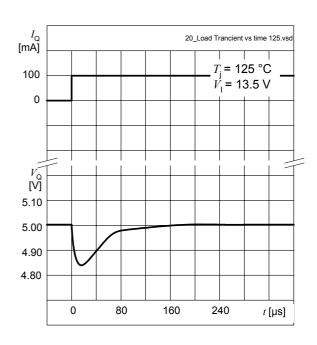




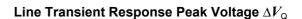
Line Regulation $\Delta V_{\rm Q}$ versus Input Voltage Change $V_{\rm I}$

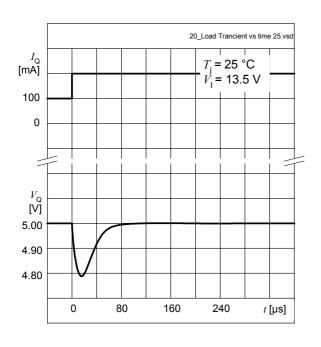


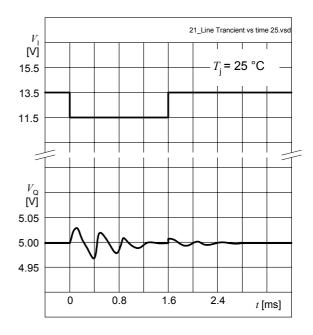
Load Transient Response Peak Voltage ΔV_{Q}



Load Transient Response Peak Voltage $\Delta V_{
m Q}$



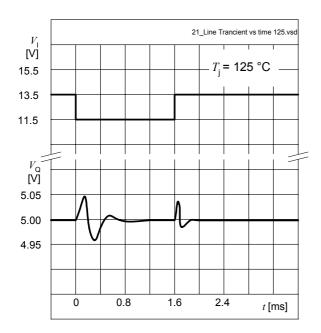






Line Transient Response Peak Voltage $\Delta V_{\rm Q}$

I





5.3 Electrical Characteristics Enable Function

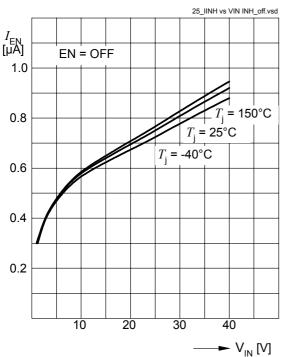
The Enable Function allows disabling/enabling the regulator via the input pin EN. The regulator is turned on in case the pin EN is connected to a voltage higher than **VEN,H**. This can be e.g. the battery voltage, whereby no additional pull-up resistor is needed. The regulator can be turned off by connecting the pin EN to a voltage less than **VEN,L**, e.g. GND.

Electrical Characteristics Enable V_i =13.5 V; T_j = -40 °C to 150 °C; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

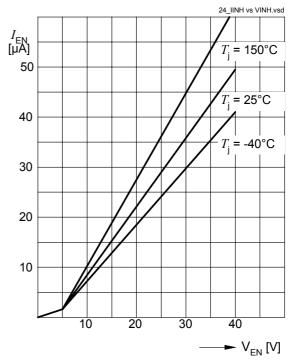
Pos.	Parameter	Symbol	Lii	Limit Values			Measuring Condition
			Min.	Тур.	Max.		
5.3.13	High Level Input Voltage	$V_{EN,H}$	3.1	_	_	V	<i>V</i> _Q ≥4.9 V
5.3.14	Low Level Input Voltage	$V_{EN,L}$	_	_	8.0	V	<i>V</i> _Q ≤0.3 V
5.3.15	High Level Input Current	$I_{EN,H}$	-	3	4	μΑ	V _{EN} = 5 V

5.4 Typical Performance Characteristics Enable Function

Enabled Input Current I_{EN} versus Input Voltage V_{I} , EN=Off



Enabled Input Current $I_{\rm EN}$ versus Enabled Input Voltage $V_{\rm EN}$





5.5 Electrical Characteristics Reset Function

The Reset function informs e.g. the microcontroller in case the output voltage has fallen below the lower threshold VRT of typ. 4.65 V. The headroom VRH between the output voltage and the reset threshold is typically 350 mV. Connecting the regulator to a battery voltage at first the reset signal remains LOW. When the output voltage has reached the reset threshold VRT the reset output RO remains still LOW for the reset delay time tRD (typ. 16 ms). Afterwards the reset output turns HIGH.

Electrical Characteristics Reset

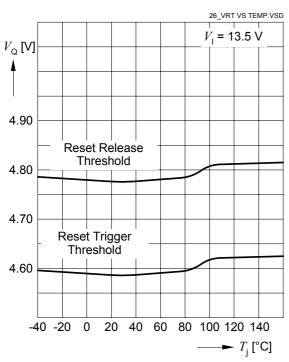
 V_1 =13.5 V; – 40 °C < T_1 < 150 °C; all voltages with respect to ground (unless otherwise specified)

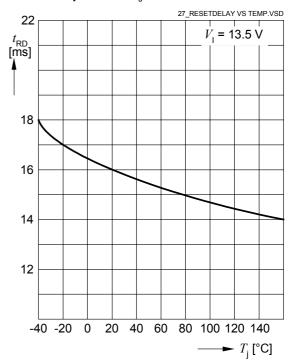
Pos.	Parameter	Symbol	Limit	Limit Values			Conditions
			Min.	Тур.	Max.		
5.5.1	Output Undervoltage Reset Switching Threshold	V_{RT}	4.50	4.65	4.80	V	$V_{\rm Q}$ decreasing $V_{\rm I}$ = 6V
5.5.2	Output Undervoltage Reset Headroom	V_{RH}	_	350	_	mV	-
5.5.3	Reset Output Low Level Voltage	V_{ROL}	_	0.2	0.4	V	$R_{\rm RO}$ = 10 k Ω ; $V_{\rm Q}$ > 1 V
5.5.4	Integrated Reset Pull Up Resistor	R_{RO}	15	30	45	kΩ	-
5.5.5	Optional External Reset Pull Up Resistor	$R_{RO,ext}$	10	-	_	kΩ	-
5.5.6	Power On Reset Delay Time	t_{RD}	10	16	22	ms	_
5.5.7	Reset Reaction Time	t_{RR}	_	_	12	μs	_



5.6 Typical Performance Characteristics Reset Function

Reset Threshold $V_{\rm RT}$ versus Junction Temperature Reset Delay $t_{\rm RD}$ versus Junction Temperature $T_{\rm J}$







Package Outlines

6 Package Outlines

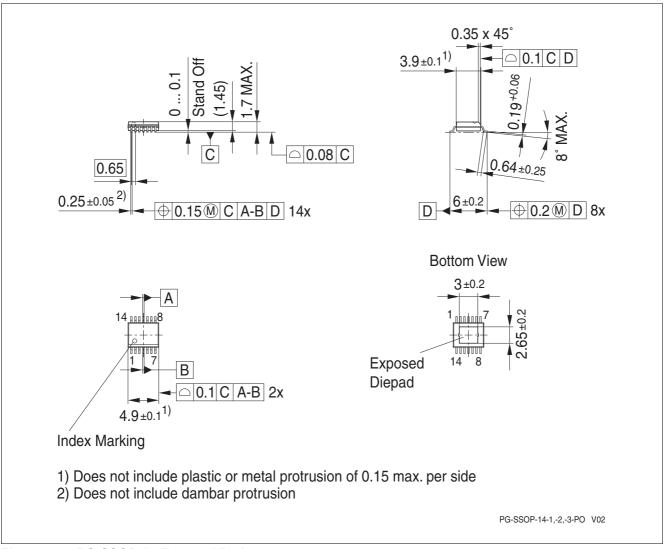


Figure 4 PG-SSOP-14 Exposed Pad



Package Outlines

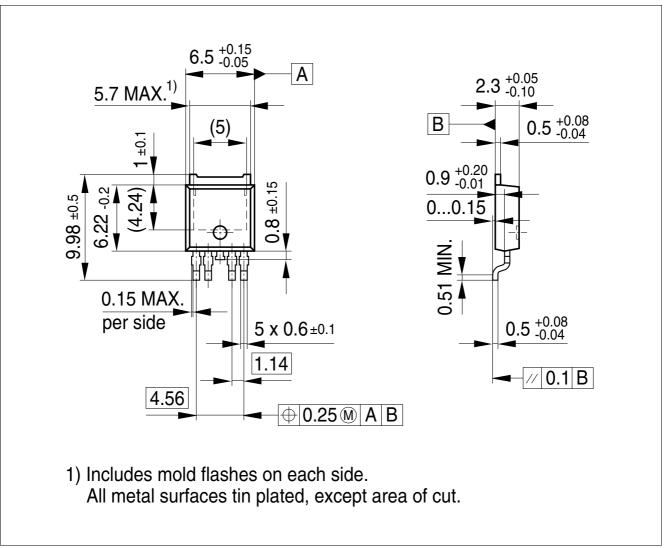


Figure 5 PG-TO252-5

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



Revision History

7 Revision History

Revision	Date	Changes
1.0	2009-06-01	initial version data sheet

Edition 2009-06-01

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